		PRODUCTS	CTS		ТҮРЕ				
	ROHM S		Semiconductor IC		BH1427GUL		1/4		
PF TY	STRUCTURE       Silicon Monolithic Integrated Circuit         PRODUCT SERIES       Wireless Audio Link LSI for Mobile Phone (FM Stereo Transmitter)         TYPE       BH1427GUL         FEATURE       • Low voltage Fast Mode I <sup>2</sup> C-BUS interface.         • Adjustment free wideband PLL frequency synthesizer (76MHz~108MHz).         • Possible to select reference clock frequency freely.         • Possible to select transmission power by serial control.         • Built-in high performance Low-pass Filter.         • Built-in pilot-tone system FM stereo modulator circuit.         • The transmission frequency is stable because it has PLL system FM transmitter circuit								
0	<ul> <li>Possible to operate in monaural mode.</li> <li>Built-in the sound muting circuit.</li> <li>O Absolute Maximum Ratings (Ta=25℃)</li> </ul>								
	Parameter	Symbo	Li	nits	Unit	Condition			
	Supply voltage	VCC	-0.3 1	o +5.5	v	Pin 2, 7, 11, 13, 25			
	Data input voltage 1	V <sub>IN-D1</sub>	-0.3 to \	/ <sub>DDIO</sub> +0.3	V	Pin 16, 19, 20			
	Data input voltage 2	V <sub>IN-D2</sub>	-0.3	o +5.5	v	Pin 17, 18			
	Power dissipation		9	960		(NOTE 1)			
	Storage temperature		-55 te	-55 to +125					
The vers Applic • ROI • The offic Sho wou	(NOTE 1) To use at a us of this document Japanese version of this docume sion. If there are any differences in cation example HM cannot provide adequate ca product described in this spe ce-automation equipment, com build you intend to use this product and directly endanger human lit trollers and other safety device	ent is the formal specifi n translation version of onfirmation of patents cification is designed imunications devices oduct with equipment fe (such as medical in	cation. A customer r this document, form s. d to be used with , electrical applian t or devices which nstruments, transp	nay use this transla al version takes pri prdinary electroni ces, and electroni require an extrer portation equipme	tion version on ority. c equipment of c toys). nely high leve nt, aerospace	or devices (such as audio- el of reliability and the mal machinery, nuclear-reacto	visual equipment		
repi	HM assumes no responsibility resentations that the circuits and ESIGN CHECK	APPROVAL				r any patent or other right: TSZ02201-BH14			
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O Operating Supply Voltage Range

Parameter	Symbol	Limits	Unit	Conditions
Operating supply voltage 1	Vcc	2.7 to 3.6	V	Pin 2, 7, 11, 25
Operating supply voltage 2	VDDIO	1.7 to 3.6	v	Pin 13
Operating temperature	Tpor	-20 to +85	ິຕ	
Audio input level	V <sub>IN-A</sub>	to -10	dBV	Pin 26, 27
Audio input frequency	f <sub>IN-A</sub>	20 to 15k	Hz	Pin 26, 27
Transmission frequency	fтx	76.0 to 108.0	MHz	100kHz step
Control terminal "H" level input voltage 1	ViH1	0.7VDDIO to VDDIO	v	Pin 16, 19, 20
Control terminal "H" level input voltage 2	V <sub>IH2</sub>	0.7V <sub>DDIO</sub> to +5.5	v	Pin 17, 18
Control terminal "L" level input voltage	VIL	GND to 0.3VDDIO	v	Pin 16, 17, 18, 19, 20

## ○ Electrical Characteristics

Unless otherwise specified Ta=25°C, V<sub>CC</sub>=3.0V, V<sub>DDIO</sub>=1.8V

Signal source :  $f_{IN}=1kHz$ ,  $V_{IN}=-20dBV$  Common condition :  $f_{TX}=90MHz$ ,  $\Delta f=\pm75kHz$ ,  $\tau=50 \mu s$ 

Parameter	Symbol	Limits			Unit	Condition	
Falancici		Min.	Тур.	Max.	Unit	Condition	
Quiescent current	la	11	16	23	mA	Tx power control is 0dB setting.	
Power down current	IPWD	-	0	1	μA	BUSEN="L"	
Channel separation	Sep	25	40	-	dB	L→R, R→L	
Signal to point ratio	SNR	60	69	-	dB	L+R	
Signal to noise ratio		61	70	_	dB	MONO	
Total harmonic distortion	THD	-	0.1	0.3	%	L+R	
Total harmonic distortion		-	0.1	0.3	%	MONO	
Transmission power level	Ρτχ	-8	-5	-2	dBm	Tx power control is 0dB setting.	
Pilot modulation rate	MP	7	11	15	%	L+R	
"H" level input current	IIH	_	_	1.0	μA	Pin 16, 19, 20 V <sub>IN</sub> =3V	
"L" level input current	լլ	-1.0	-	-	μA	Pin 16, 19, 20 V <sub>IN</sub> =0V	
"L" level output voltage	Vol	_	-	0.2V <sub>DDIO</sub>	. <b>V</b>	Pin 18 lo=3mA	

◎ This product is not designed for protection against radioactive rays.

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◎ The specification of transmission output level be based on the Radio Law in every country and the area.



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○ Cautions on use

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(1) Absolute maximum ratings

If applied voltage, operating temperature range, or other absolute maximum ratings are exceeded, the LSI may be damaged. Do not apply voltages or temperatures that exceed the absolute maximum ratings. If you think of a case in which absolute maximum ratings are exceeded, enforce fuses or other physical safety measures and investigate how not to apply the conditions under which absolute maximum ratings are exceeded to the LSI.

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(2) GND potential

Make the GND pin voltage such that it is the lowest voltage even when operating below it. Actually confirm that the voltage of each pin does not become a lower voltage than the GND pin, including transient phenomena.

(3) Thermal design

Perform thermal design in which there are adequate margins by taking into account the allowable power dissipation in actual states of use.

(4) Shorts between pins and misinstallation

When mounting the LSI on a board, pay adequate attention to orientation and placement discrepancies of the LSI. If it is misinstalled and the power is turned on, the LSI may be damaged. It also may be damaged if it is shorted by a foreign substance coming between pins of the LSI or between a pin and a power supply or a pin and a GND.

(5) Operation in strong magnetic fields

Adequately evaluate use in a strong magnetic field, since there is a possibility of malfunction.

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	PRODUCTS	TYPE Jisso Information for PAGE				
10Hf	Semiconductor	BH1427GUL 1/				
	Jisso Information ckage : VCSP50					
2. Tape 3. Stor 4. Mark 5. Reco 6. Foot	acture and materials e and Reel informations rage conditions king lot number commended soldering conditions torint dimensions	1/4 page 1/4 ~ 3/4 page 3/4 page 3/4 page 3/4 page 4/4 page				
7. Rega	arding the underfill material	4/4 page 4/4 page				
1. Structure and	l materials					
<ul> <li><b>2. Tape and Ree</b></li> <li>2. 1. Packing specific</li> <li>Tape</li> <li>Quantity</li> <li>Direction of feed</li> <li>2. 2. Tape and Re</li> </ul>		No.       Item       Materials         ①       Die       Silicon         ②       Cu Post       Cu         ③       Encapsulation       Epoxy Resin         ④       Ext. terminal       Sn-3Ag-0.5Cu Solder         ⑤       Encapsulation       Polyamide-imide Resin         ⑥       Marking       Laser Marking         Dehydrated weight :       0.009g         〇       〇       〇         ●       1234       1234         ●       1234       1234         ●       1234       1234         ●       1234       1234         ●       1234       1234         ●       1234       1234         ●       1234       1234         ●       1       1         ●       1       1         ●       1       1         ●       1       1         ●       1       1         ●       1       1         ●       1       1         ●       1       1       1         ●       1       1       1         ●       1       1       1<				
2. 2. 1. Tape and						







RCHT PRODUCTS Semiconducto		<sup>TYPE</sup> Jisso Information for BH1427GUL			
6. Footprint dimensions (Optimize footprint dime	ensions to the board design and	soldering condition)			
	Symbol	Reference Value			
	e	0.50			
0 0 0 0 <del>0                             </del>	0 b3	0.25			
0 0 0 0 <del>0 0 0 0</del>	SD	0.25			

## 7. Regarding the underfill material

There are some cases that the underfill material is applied as purpose to reinforce the soldered junction of the package. Since the mount reliability depends on the resin material or coating condition, it may deteriorate on the contrary. Therefore, it is necessary to evaluate it sufficiently for its application.

In term of the coating condition, it is preferable that there is an enough material beyond the each four sides of a packeage.

<Preferable example> <Non preferable example> . . . . . . 00000

(There is a Underfill resin evenly at each four sides.)

## 8. External dimentions



SE

0.25

(Unit:mm)

